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November 2013

FQP50N06L

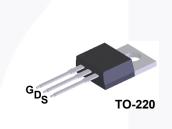
N-Channel QFET[®] MOSFET 60 V, 52.4 A, 21 m Ω

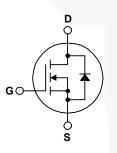
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 52.4 A, 60 V, $R_{DS(on)}$ = 21 m Ω (Max.) @ V_{GS} = 10 V, I_D = 26.2 A
- Low Gate Charge (Typ. 24.5 nC)
- Low Crss (Typ. 90 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating





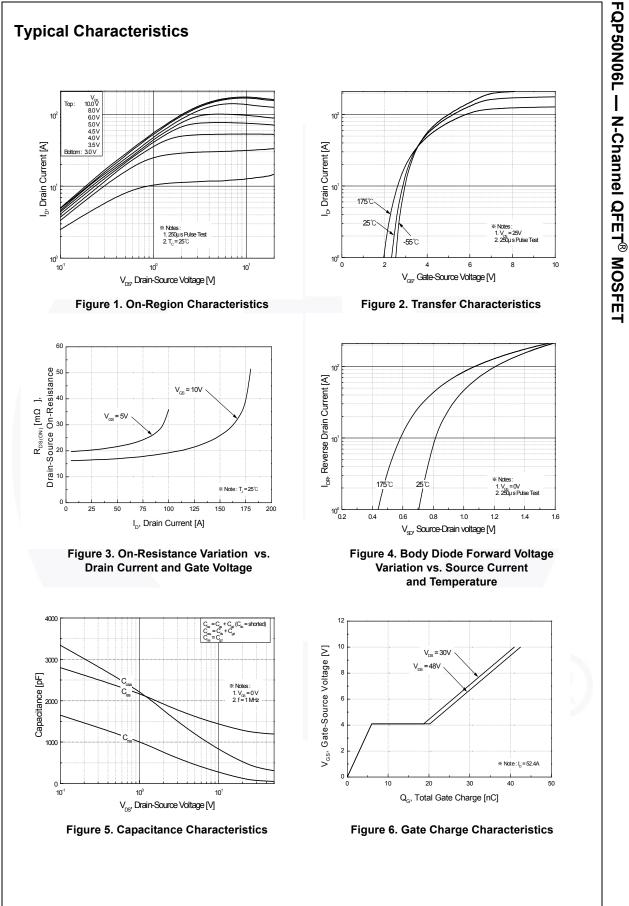
Absolute Maximum Ratings T_c = 25°C unless otherwise noted.

Symbol	Parameter		FQP50N06L	Unit
V _{DSS}	Drain-Source Voltage		60	V
I _D	Drain Current - Continuous ($T_C = 25^\circ$	C)	52.4	A
	- Continuous (T _C = 100	37.1	A	
I _{DM}	Drain Current - Pulsed	(Note 1)	210	A
V _{GSS}	Gate-Source Voltage		± 20	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	990	mJ
I _{AR}	Avalanche Current	(Note 1)	52.4	A
E _{AR}	Repetitive Avalanche Energy	(Note 1)	12.1	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	7.0	V/ns
PD	Power Dissipation (T _C = 25°C)		121	W
	- Derate above 25°C	0.81	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C
ΤL	Maximum Lead Temperature for Solderin 1/8" from Case for 5 seconds	g,	300	°C

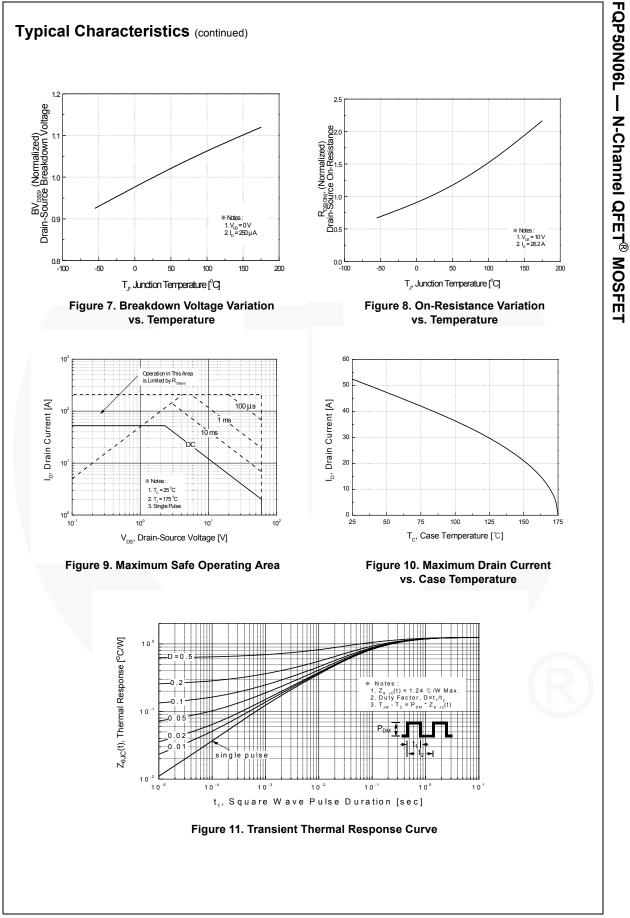
Thermal Characteristics

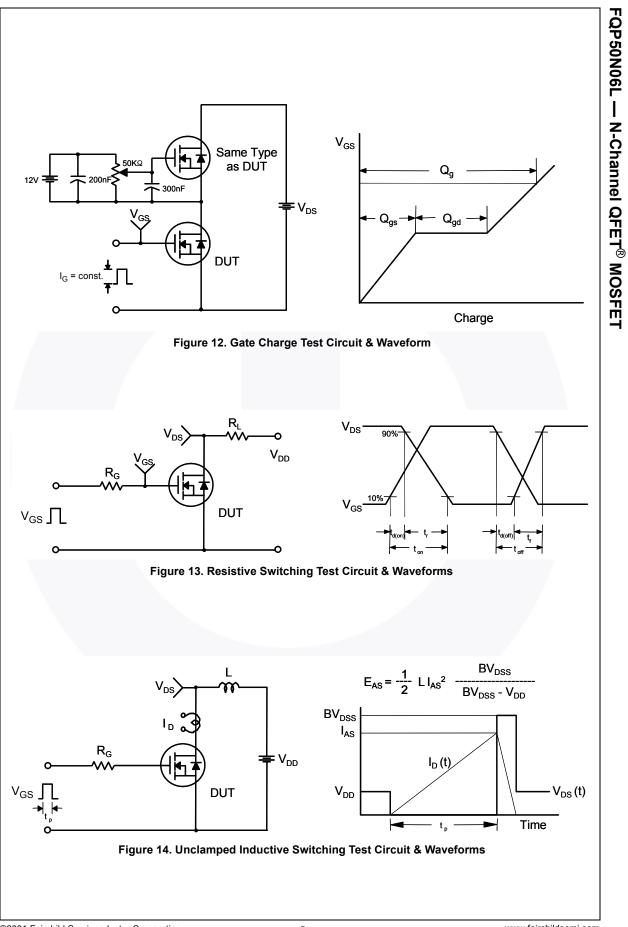
Symbol	Parameter	FQP50N06L	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	1.24	°C/W	
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

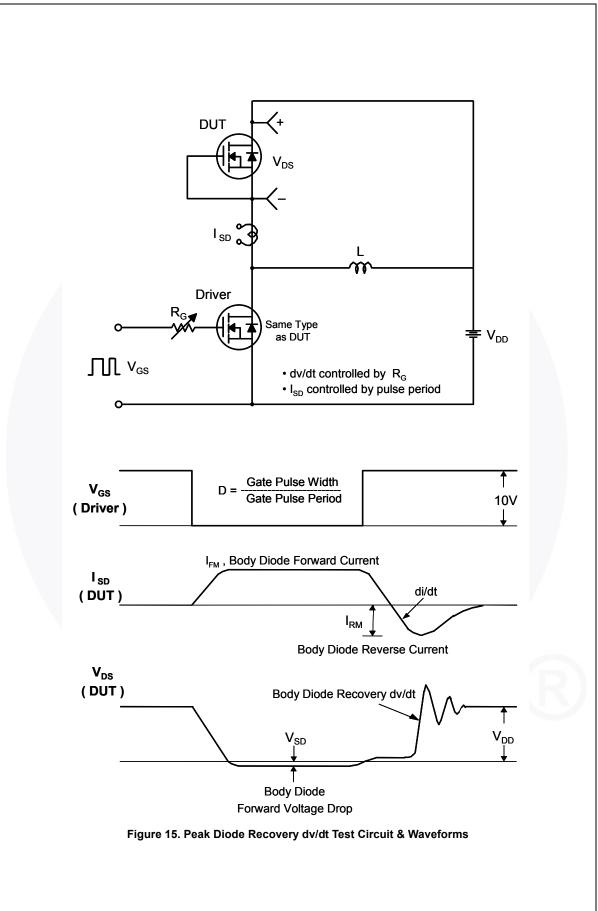
Part Number Top Mark Packag		Package	Packing Method	Reel Size	Tape Width		th Q	Quantity	
FQP50	FQP50N06L FQP50N06L TO-220		Tube N/A		N/A		5	50 units	
lectri	cal Cl	haracteristics	T _C = 25°C	unless otherwise noted.					
Symbol		Parameter		Test Condi	tions	Min	Тур	Мах	Unit
Off Cha	aracter	istics							
V _{DSS}	1	Source Breakdown V	oltage	ge V _{GS} = 0 V, I _D = 250 μA		60			V
BV _{DSS} ΔT _J		down Voltage Tempe	n Voltage Temperature		$I_D = 250 \ \mu$ A, Referenced to 25°C		0.06		V/°C
DSS	Zero Gate Voltage Drain Current		V _{DS} = 60 V, V _{GS} = 0) V			1	μA	
			V _{DS} = 48 V, T _C = 15	50°C			10	μA	
GSSF	Gate-E	Body Leakage Currer	nt, Forward	V_{GS} = 20 V, V_{DS} = 0	V			100	nA
GSSR	Gate-E	Body Leakage Currer	nt, Reverse	V_{GS} = -20 V, V_{DS} =	0 V			-100	nA
On Cha	aracter	istics							
/ _{GS(th)}	1	hreshold Voltage		$V_{DS} = V_{GS}, I_{D} = 250$) μΑ	1.0		2.5	V
R _{DS(on)}		Drain-Source		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 26.$			0.017	0.021	
20(011)	On-Resistance			$V_{GS} = 5 V, I_D = 26.2 A$			0.020	0.025	Ω
IFS	Forwa	rd Transconductance	•	V _{DS} = 25 V, I _D = 26.	2 A		40		S
Junam	ic Cha	racteristics							
		Capacitance					1250	1630	pF
- ISS - OSS		t Capacitance		$V_{DS} = 25 V, V_{GS} = 0$ f = 1.0 MHz	J V,		445	580	p. pF
rss		se Transfer Capacita	nce	f = 1.0 MHz			90	120	p. pF
		· · · ·							
Switch	ing Ch	aracteristics							
d(on)	Turn-C	On Delay Time		V _{DD} = 30 V, I _D = 26.2 A,			20	50	ns
-	Turn-C	In Rise Time		$R_G = 25 \Omega$,		380	770	ns
d(off)	Turn-C	Off Delay Time		0			80	170	ns
	Turn-C	Off Fall Time			(Note 4)		145	300	ns
ζ ^g	Total C	Bate Charge		V_{DS} = 48 V, I _D = 52.4 A, V _{GS} = 5 V (Note 4)		-	24.5	32	nC
ک _{gs}	Gate-S	Source Charge					6		nC
2 _{gd}	Gate-I	Drain Charge					14.5	/	nC
Drain 6		Diada Charact	riation on	d Maximum Rat	lingo				
					lings			52.4	А
S SM		Maximum Continuous Drain-Source Diode Forward Current Maximum Pulsed Drain-Source Diode Forward Current				210	A		
sm / _{SD}		Source Diode Forwar		V_{GS} = 0 V, I _S = 52.4 A				1.5	V
		se Recovery Time	u voltage	$V_{GS} = 0 V, I_S = 52.4 A$ $V_{GS} = 0 V, I_S = 52.4 A,$ $dI_F / dt = 100 A/\mu s$			65		
m)		se Recovery Time					125		ns nC
ל ^{גג}	Revers	se necovery charge					120		no

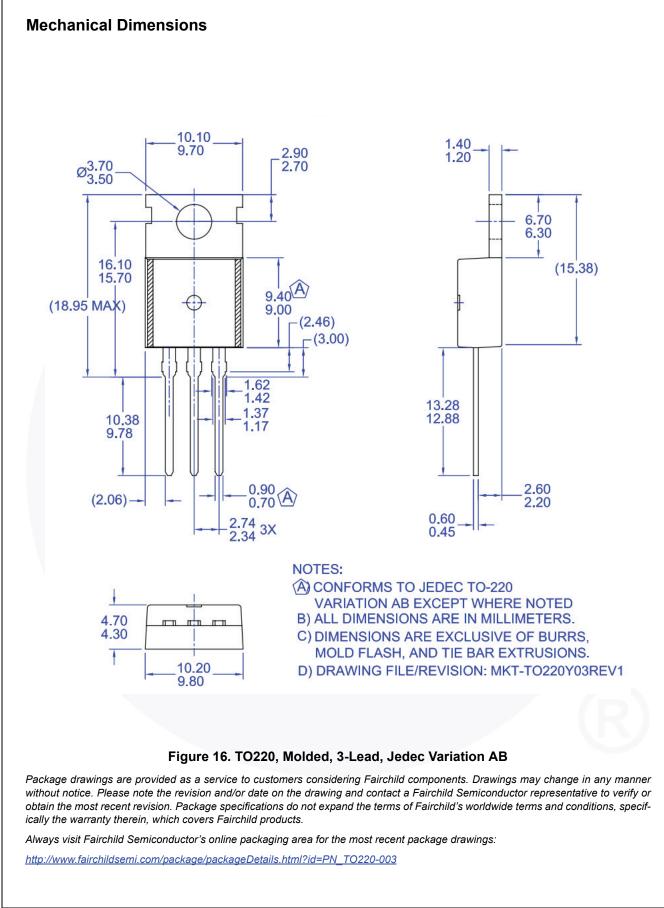


3











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FQP50N06L — N-Channel QFET[®] MOSFET

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